

L Number	Hits	Search Text	DB	Time stamp
25	44	((p-type near GaAs near3 substrate) or (p-GaAs near3 substrate)) and pin	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:21
26	20	p-type same (ZnSe/ZnTe near5 superlattice)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:19
27	3008312	p-(ZnSe/ZnTe) near3 superlattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:20
28	1421	((p-type near GaAs near3 substrate) or (p-GaAs near3 substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:21
29	1421	(p-(ZnSe/ZnTe) near3 superlattice) and (((p-type near GaAs near3 substrate) or (p-GaAs near3 substrate)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:21
30	101	((p-(ZnSe/ZnTe) near3 superlattice) and (((p-type near GaAs near3 substrate) or (p-GaAs near3 substrate)))) and (photodiode or photodetector)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/05/28 15:22